



FMMT560

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### **500V PNP HIGH VOLTAGE TRANSISTOR IN SOT23**

### **Features**

- BV<sub>CEO</sub> > -500V
- I<sub>C</sub> = -150mA high Continuous Collector Current
- I<sub>CM</sub> Up to -500mA Peak Pulse Current
- Excellent h<sub>FE</sub> Characteristics up to I<sub>C</sub> = -100mA
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- An Automotive Compliant Part is Available Under Separate Datasheet (FMMT560Q)

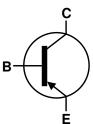
### **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (§3)
- Weight 0.008 grams (Approximate)

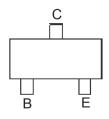




Top View



Device Symbol



Top View Pin-Out

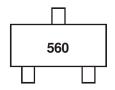
## **Ordering Information** (Note 4)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
FMMT560TA	AEC-Q101	560	7	8	3,000
FMMT560TC	AEC-Q101	560	13	8	10,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**



560 = Product Type Marking Code



## **Absolute Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	-500	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-500	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current	Ic	-150	mA
Peak Pulse Current	I <sub>CM</sub>	-500	mA

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	$P_{D}$	500	mW
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{ heta JA}$	250	°C/W
Thermal Resistance, Junction to Lead (Note 6)		$R_{ heta JL}$	194	°C/W
Operating and Storage Temperature Range	$T_{J_i}T_{STG}$	-55 to +150	°C	

## ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge – Machine Model	ESD MM	400	V	С

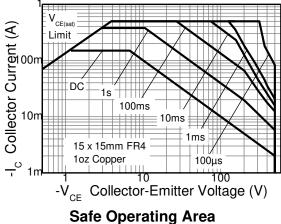
Notes:

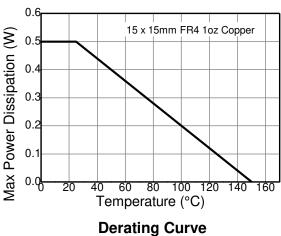
<sup>5.</sup> For a device mounted with the collector lead on 15mm x 15mm 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

<sup>6.</sup> Thermal resistance from junction to solder-point (at the end of the collector lead).
7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

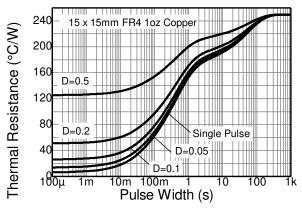


# Thermal Characteristics and Derating Information









**Transient Thermal Impedance** 

**Pulse Power Dissipation** 



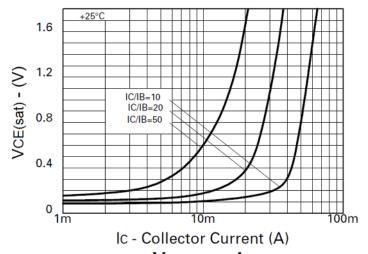
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

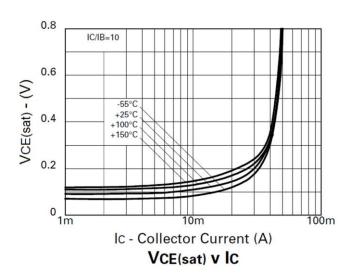
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-500	_		V	$I_{C} = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 8)	BV <sub>CEO</sub>	-500	_	_	V	$I_C = -1mA$
Emitter-Base Breakdown Voltage	$BV_EBO$	-7	_	_	V	$I_E = -100 \mu A$
Collector Cutoff Current	I <sub>CBO</sub>	_	_	-100	nA	V <sub>CB</sub> = -500V
Emitter Cutoff Current	I <sub>EBO</sub>	_	_	-100	nA	$V_{EB} = -5V$
Static Forward Current Transfer Ratio (Note 8)	h <sub>FE</sub>	100 80 —	_ _ 15	300 300 —	_	$I_C = -1mA$ , $V_{CE} = -10V$ $I_C = -50mA$ , $V_{CE} = -10V$ $I_C = -100mA$ , $V_{CE} = -10V$
Collector-Emitter Saturation Voltage (Note 8)	V <sub>CE(SAT)</sub>	_	_	-200 -500	mV	$I_C = -20mA$ , $I_B = -2mA$ $I_C = -50mA$ , $I_B = -10mA$
Base-Emitter Saturation Voltage (Note 8)	$V_{BE(SAT)}$	_	_	-0.9	V	$I_C = -50 \text{mA}, I_B = -10 \text{mA}$
Base-Emitter Turn-On Voltage (Note 8)	V <sub>BE(ON)</sub>	_	_	-0.9	V	$I_C = -50 \text{mA}, V_{CE} = -10 \text{V}$
Output Capacitance	C <sub>OBO</sub>	_	_	8	pF	$V_{CB} = -20V$ , $f = 1MHz$
Transition Frequency	f⊤	60	_	_	MHz	$V_{CE} = -20V$ , $I_C = -10mA$ , $f = 50MHz$
Turn-On Time	t <sub>ON</sub>	_	110	_	ns	$V_{CE} = -100V, I_{C} = -50mA,$
Turn-Off Time	t <sub>OFF</sub>	_	1.5	_	μs	$I_{B1} = -5mA, I_{B2} = 10mA$

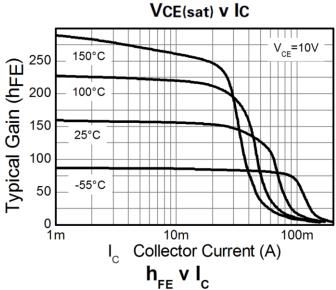
Note: 8. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%

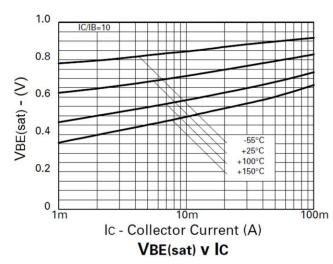


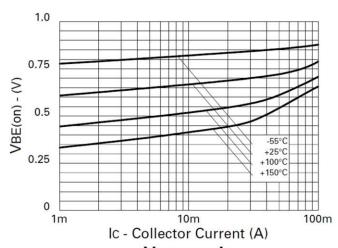
## Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)









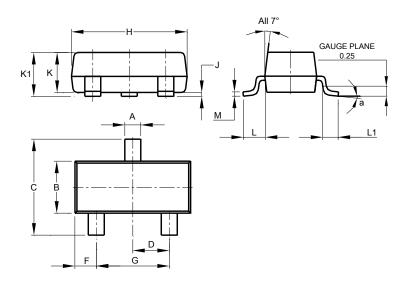




## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### SOT23

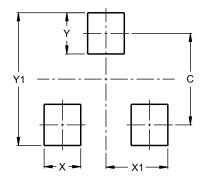


SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
J	0.013	0.10	0.05		
K	0.890	1.00	0.975		
K1	0.903	1.10	1.025		
L	0.45	0.61	0.55		
L1	0.25	0.55	0.40		
М	0.085	0.150	0.110		
а	0°	8°	_		
All Dimensions in mm					

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Υ	0.9
Y1	2.9

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.



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